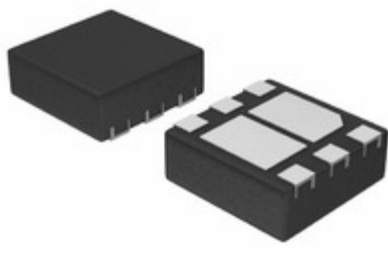

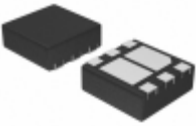
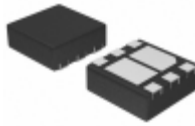
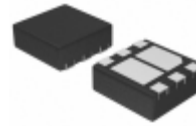
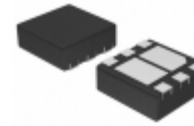
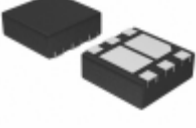
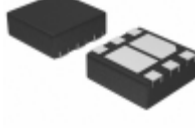
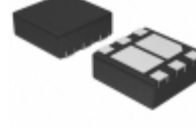
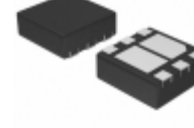
	<h2 style="color: red;">NTLJD4116NT1G</h2>	
	<b>Hersteller-Teilenummer:</b>	<a href="#">NTLJD4116NT1G</a>
	<b>Hersteller / Marke:</b>	<a href="#">AMI Semiconductor / ON Semiconductor</a>
	<b>Teil der Beschreibung:</b>	MOSFET 2N-CH 30V 2.5A 6-WDFN
<b>Datenblätter:</b>	 <a href="#">NTLJD4116NT1G.pdf</a>	
<b>RoHs Status:</b>	Bleifrei / RoHS-konform	
<b>Lagerzustand:</b>	New original, 54428 pcs Stock Available.	
<b>Liefern von:</b>	Hong Kong	
<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

### Spezifikationen

Teilenummer	<a href="#">NTLJD4116NT1G</a>
Hersteller	<a href="#">AMI Semiconductor / ON Semiconductor</a>
Beschreibung	MOSFET 2N-CH 30V 2.5A 6-WDFN
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	54428 pcs Stock
Serie	-
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	710mW
Verpackung / Gehäuse	6-WDFN Exposed Pad
Supplier Device-Gehäuse	6-WDFN (2x2)
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	2.5A
Rds On (Max) @ Id, Vgs	70 mOhm @ 2A, 4.5V
VGS (th) (Max) @ Id	1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	6.5nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	427pF @ 15V
Verpackung	Tape & Reel (TR)

NTLJD4116NT1G ist neu im Original, Suche NTLJD4116NT1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTLJD4116NT1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTLJD4116NT1G: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>NTLJD4150PTBG</b> AMI Semiconductor / ON Semiconductor MOSFET 2P-CH 30V 1.8A 6WDFN</p>	 <p><b>NTLJD3181PZTBG</b> AMI Semiconductor / ON Semiconductor MOSFET 2P-CH 20V 2.2A 6WDFN</p>	 <p><b>NTLJF3117PTAG</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 20V 2.3A 6-WDFN</p>	 <p><b>NTLJD3183CZTBG</b> AMI Semiconductor / ON Semiconductor MOSFET N/P-CH 20V 6WDFN</p>
 <p><b>NTLJF3118NTAG</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 20V 2.6A 6-WDFN</p>	 <p><b>NTLJF3117PT1G</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 20V 2.3A 6-WDFN</p>	 <p><b>NTLJD3182FZTBG</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 20V 2.2A 6-WDFN</p>	 <p><b>NTLJD3182FZTAG</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 20V 2.2A 6-WDFN</p>

### heiße Teile

Mehr

ADR540ARTZ-REEL7	BCM20733A1KFB1G-P11	BZT52C18-V-GS08	D 2301N2400T	EL2250LS-T13
KA5M0365RYDTU	LTC6652AIMS8-3#TRPBF	D MF-MSMF110/24X-2	MJ150BX120	MMBZ33VAL-7
N105CH15	N282CH24JOO	NTLGD3502NT1G	NTLGD3502NT2G	NTLJ3113PT1G
D NTLJD2105LTBG	NTLJD3115PT1G	NTLJD3115PTAG	NTLJD3119CT1G	NTLJD3119CTAG
NTLJD3119CTBG	NTLJF3117PT1G	NTLJF4156NT1G	NTLJF4156NTAG	NTLJS2103P
NTLJS2103PTAG	NTLJS2103PTBG	D NTLJS3113P	NTLJS3113PT1G	NTLJS3113PTAG
NTLJS3A18PZTWG	D NTLJS4114NT1G	NTLJS4114NTAG	NTLJD4901NF	NTLJD4901NFTWG
NTLTD7900NR2G	NTLTD7900ZR2	NTLTD7900ZR2G	NTLUD3A260PZTAG	NTLUD3A50PZTAG
NTLUF4189NZTAG	NTLUS3A18PZTAG	NTLUS3A40PZTAG	D NTLUS3A40PZTBG	NTLUS3A90PZTAG
NTLUS4930NTAG	P87C51X2FBD	PS8302L-V-E3-A	VBO105-12N07	WG18019R20

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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